

CEA3055-VB Datasheet

N-Channel 60-V (D-S) MOSFET

PRODUCT SUMMARY						
V _{DS} (V)	$R_{DS(on)}\left(\Omega\right)$	I _D (A)				
60	0.030 at V _{GS} = 10 V	8.0				
	0.034 at V _{GS} = 4.5 V	6.5				

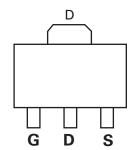
FEATURES

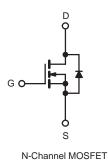
 Halogen-free According to IEC 61249-2-21 Definition



RoHS COMPLIANT

- Trench Power MOSFETs
- 175 °C Maximum Junction Temperature
- Compliant to RoHS Directive 2002/95/EC





ABSOLUTE MAXIMUM RATINGS T _A = 25 °C, unless otherwise noted								
Parameter	Symbol	10 s	Steady State	Unit				
Drain-Source Voltage	V_{DS}	6	V					
Gate-Source Voltage	V_{GS}	±						
Continuous Drain Current (T _{.I} = 175 °C) ^a	T _A = 25 °C	I _D	8.0	7.0				
Continuous Diain Current (1 j = 175 C)	T _A = 70 °C	טי	6.4	5.6	Α			
Pulsed Drain Current	I _{DM}	4	^					
Avalanche Current	I _{AS}	1						
Single Pulse Avalanche Energy	E _{AS}	1	mJ					
Mariana Barra Biaria di ang	T _A = 25 °C	P _D	3.3	1.7	W			
Maximum Power Dissipation ^a	T _A = 70 °C] 'D	2.3	1.2	VV			
Operating Junction and Storage Temperature Range	T _J , T _{stg}	- 55 t	°C					

THERMAL RESISTANCE RATINGS							
Parameter	Symbol	Typical	Maximum	Unit			
Mariana la sation to Ambient 3	t ≤ 10 s	R _{thJA}	36	45			
Maximum Junction-to-Ambient ^a	Steady State	'`thJA	75	90	°C/W		
Maximum Junction-to-Foot (Drain)	Steady State	R_{thJF}	17	20			

Notes:

a. Surface Mounted on 1" x 1" FR4 board.

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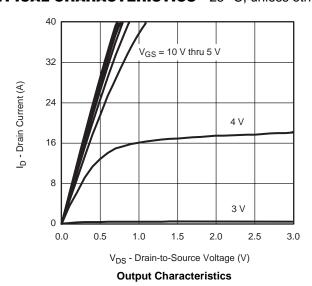
Parameter	Symbol	Test Conditions N		Тур.	Max.	Unit	
Static							
Drain-Source Breakdown Voltage	V_{DS}	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$	60			V	
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250 \mu A$	1		3	V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA	
Zero Gate Voltage Drain Current	l	$V_{DS} = 60 \text{ V}, V_{GS} = 0 \text{ V}$			1	μΑ	
Zero Gate voltage Drain Current	IDSS	$V_{DS} = 60 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55 ^{\circ}\text{C}$			20		
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	40			Α	
		$V_{GS} = 10 \text{ V}, I_D = 6.0 \text{ A}$		0.030			
Davis Course On Otata Basistana 3	D	$V_{GS} = 10 \text{ V}, I_D = 6.0 \text{ A}, T_J = 125 \text{ °C}$		0.035		Ω	
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = 10 \text{ V}, I_D = 6.0 \text{ A}, T_J = 175 ^{\circ}\text{C}$		0.040			
	•	$V_{GS} = 4.5 \text{ V}, I_D = 5.1 \text{ A}$	0.034				
Forward Transconductance ^a	9 _{fs}	$V_{DS} = 15 \text{ V}, I_D = 6.0 \text{ A}$		25		S	
Diode Forward Voltage ^a	V_{SD}	I _S = 1.7 A, V _{GS} = 0 V		0.8	1.2	V	
Dynamic ^b			•				
Total Gate Charge	Q_g			18	27		
Gate-Source Charge	Q_{gs}	$V_{DS} = 30 \text{ V}, V_{GS} = 10 \text{ V}, I_{D} = 6.0 \text{ A}$		3.4		nC	
Gate-Drain Charge	Q_{gd}			5.3			
Gate Resistance R _g		$V_{GS} = 0.1 \text{ V, } f = 5 \text{ MHz}$	5 MHz 0.5		2.4	Ω	
Turn-On Delay Time	t _{d(on)}			10	20		
Rise Time	t _r	V_{DD} = 30 V, R_L = 30 Ω		10	20		
Turn-Off Delay Time	t _{d(off)}	$I_D\cong$ 1 A, V_{GEN} = 10 V, R_g = 6 Ω		25	50	ns	
Fall Time	t _f			12	24		
Source-Drain Reverse Recovery Time	t _{rr}	I _F = 1.7 A, dI/dt = 100 A/μs		50	80		

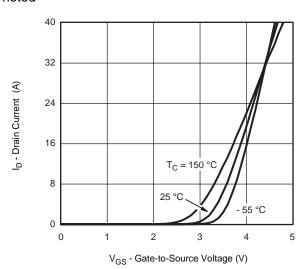
Notes:

- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

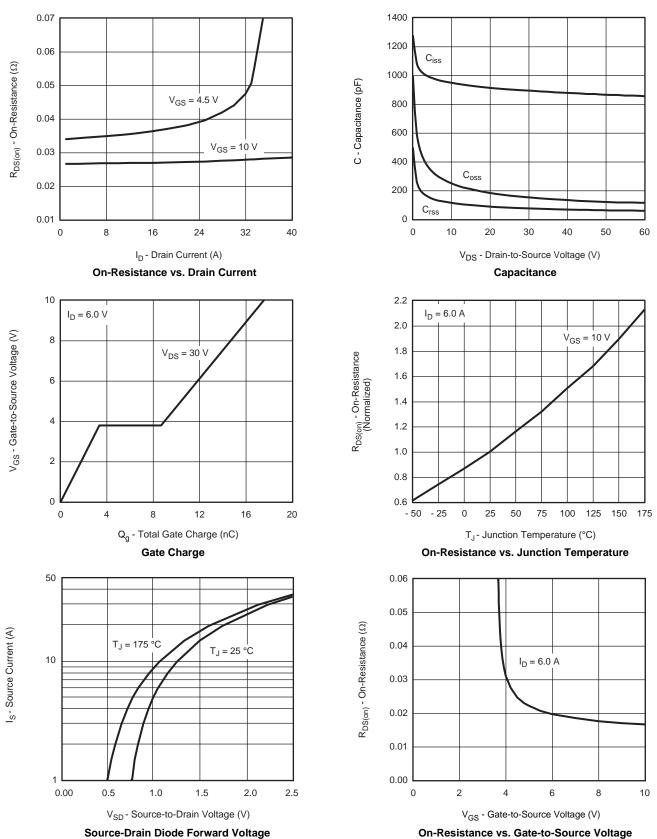




Transfer Characteristics

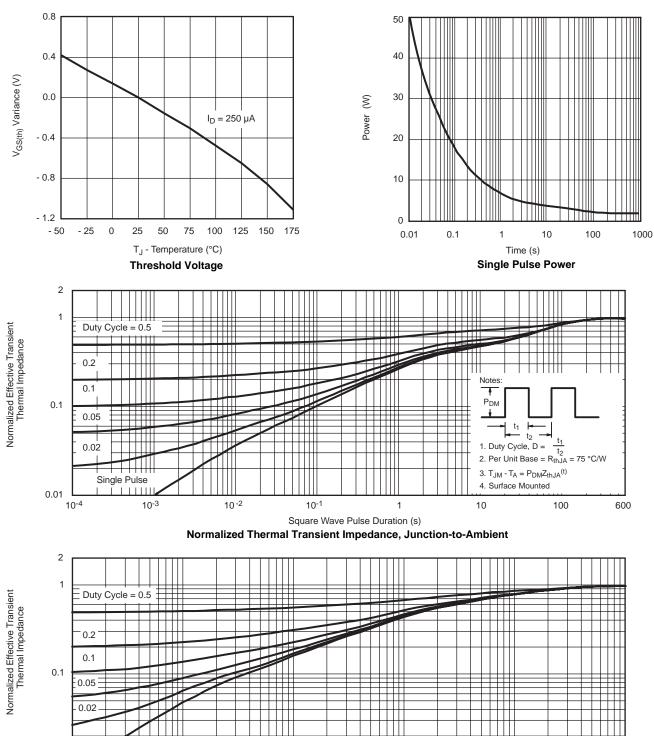


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Square Wave Pulse Duration (s)

Normalized Thermal Transient Impedance, Junction-to-Foot

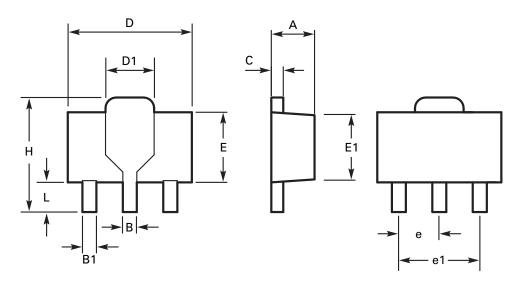
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Single Pulse

10-3



Package outline - SOT89



DIM	Millin	neters	Inc	hes	DIM	M Millimeters		Inches	
	Min	Max	Min	Max		Min	Max	Min	Max
Α	1.40	1.60	0.550	0.630	Е	2.29	2.60	0.090	0.102
В	0.44	0.56	0.017	0.022	E1	2.13	2.29	0.084	0.090
B1	0.36	0.48	0.014	0.019	е	1.50 BSC		0.059 BSC	
С	0.35	0.44	0.014	014 0.017 e1		3.00 BSC		0.118	BSC
D	4.40	4.60	0.173	0.181	Н	3.94	4.25	0.155	0.167
D1	1.62	1.83	0.064	0.072	L	0.89	1.20	0.035	0.047

Note: Controlling dimensions are in millimeters. Approximate dimensions are provided in inches

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